

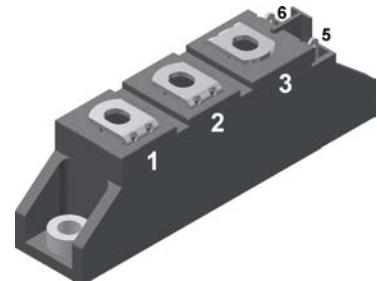
# Thyristor Module

$V_{RRM}$  = 2x 1400 V  
 $I_{TAV}$  = 49 A  
 $V_T$  = 1,34 V

## Phase leg

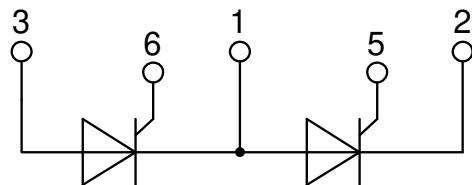
### Part number

**MCC44-14io8B**



Backside: isolated

 E72873



### Features / Advantages:

- Thyristor for line frequency
- Planar passivated chip
- Long-term stability
- Direct Copper Bonded Al2O3-ceramic

### Applications:

- Line rectifying 50/60 Hz
- Softstart AC motor control
- DC Motor control
- Power converter
- AC power control
- Lighting and temperature control

### Package: TO-240AA

- Isolation Voltage: 4800 V~
- Industry standard outline
- RoHS compliant
- Soldering pins for PCB mounting
- Base plate: DCB ceramic
- Reduced weight
- Advanced power cycling

### Disclaimer Notice

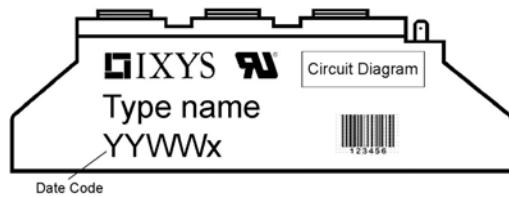
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**Thyristor**

Symbol	Definition	Conditions	Ratings			
			min.	typ.	max.	
$V_{RSM/DSM}$	max. non-repetitive reverse/forward blocking voltage	$T_{VJ} = 25^\circ C$			1500	V
$V_{RRM/DRM}$	max. repetitive reverse/forward blocking voltage	$T_{VJ} = 25^\circ C$			1400	V
$I_{R/D}$	reverse current, drain current	$V_{R/D} = 1400 V$ $V_{R/D} = 1400 V$	$T_{VJ} = 25^\circ C$ $T_{VJ} = 125^\circ C$		100 5	$\mu A$ mA
$V_T$	forward voltage drop	$I_T = 100 A$ $I_T = 200 A$ $I_T = 100 A$ $I_T = 200 A$	$T_{VJ} = 25^\circ C$ $T_{VJ} = 125^\circ C$		1,34 1,75 1,34 1,80	V V
$I_{TAV}$	average forward current	$T_C = 85^\circ C$	$T_{VJ} = 125^\circ C$		49	A
$I_{T(RMS)}$	RMS forward current	180° sine			77	A
$V_{TO}$ $r_T$	threshold voltage slope resistance } for power loss calculation only		$T_{VJ} = 125^\circ C$		0,85 5,3	V $m\Omega$
$R_{thJC}$	thermal resistance junction to case				0,53	K/W
$R_{thCH}$	thermal resistance case to heatsink			0,2		K/W
$P_{tot}$	total power dissipation		$T_C = 25^\circ C$		180	W
$I_{TSM}$	max. forward surge current	$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$ $t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$ $t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$ $t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$	$T_{VJ} = 45^\circ C$ $V_R = 0 V$ $T_{VJ} = 125^\circ C$ $V_R = 0 V$		1,15 1,24 980 1,06	kA kA
$I^2t$	value for fusing	$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$ $t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$ $t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$ $t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$	$T_{VJ} = 45^\circ C$ $V_R = 0 V$ $T_{VJ} = 125^\circ C$ $V_R = 0 V$		6,62 6,40 4,80 4,63	$kA^2s$ $kA^2s$ $kA^2s$ $kA^2s$
$C_J$	junction capacitance	$V_R = 400 V$ $f = 1 \text{ MHz}$	$T_{VJ} = 25^\circ C$	54		pF
$P_{GM}$	max. gate power dissipation	$t_p = 30 \mu s$ $t_p = 300 \mu s$	$T_C = 125^\circ C$		10 5 0,5	W W W
$P_{GAV}$	average gate power dissipation					
$(di/dt)_{cr}$	critical rate of rise of current	$T_{VJ} = 125^\circ C; f = 50 \text{ Hz}$ repetitive, $I_T = 150 A$ $t_p = 200 \mu s; di_G/dt = 0,45 A/\mu s;$ $I_G = 0,45 A; V_D = \frac{2}{3} V_{DRM}$ non-repet., $I_T = 49 A$			150	$A/\mu s$
$(dv/dt)_{cr}$	critical rate of rise of voltage	$V_D = \frac{2}{3} V_{DRM}$ $R_{GK} = \infty$ ; method 1 (linear voltage rise)	$T_{VJ} = 125^\circ C$		1000	$V/\mu s$
$V_{GT}$	gate trigger voltage	$V_D = 6 V$	$T_{VJ} = 25^\circ C$ $T_{VJ} = -40^\circ C$		1,5 1,6	V V
$I_{GT}$	gate trigger current	$V_D = 6 V$	$T_{VJ} = 25^\circ C$ $T_{VJ} = -40^\circ C$		100 200	mA mA
$V_{GD}$	gate non-trigger voltage	$V_D = \frac{2}{3} V_{DRM}$	$T_{VJ} = 125^\circ C$		0,2	V
$I_{GD}$	gate non-trigger current				10	mA
$I_L$	latching current	$t_p = 10 \mu s$ $I_G = 0,45 A; di_G/dt = 0,45 A/\mu s$	$T_{VJ} = 25^\circ C$		450	mA
$I_H$	holding current	$V_D = 6 V$ $R_{GK} = \infty$	$T_{VJ} = 25^\circ C$		200	mA
$t_{gd}$	gate controlled delay time	$V_D = \frac{1}{2} V_{DRM}$ $I_G = 0,45 A; di_G/dt = 0,45 A/\mu s$	$T_{VJ} = 25^\circ C$		2	$\mu s$
$t_q$	turn-off time	$V_R = 100 V; I_T = 150 A; V_D = \frac{2}{3} V_{DRM}$ $T_{VJ} = 100^\circ C$ $di/dt = 10 A/\mu s; dv/dt = 20 V/\mu s; t_p = 200 \mu s$		150		$\mu s$

**Package TO-240AA**
**Ratings**

Symbol	Definition	Conditions	min.	typ.	max.	Unit
$I_{RMS}$	<i>RMS current</i>	per terminal			200	A
$T_{VJ}$	<i>virtual junction temperature</i>		-40		125	°C
$T_{op}$	<i>operation temperature</i>		-40		100	°C
$T_{stg}$	<i>storage temperature</i>		-40		125	°C
<b>Weight</b>				81		g
$M_D$	<i>mounting torque</i>		2,5		4	Nm
$M_T$	<i>terminal torque</i>		2,5		4	Nm
$d_{Spp/App}$	<i>creepage distance on surface   striking distance through air</i>		<i>terminal to terminal</i>	13,0	9,7	mm
$d_{Spb/Apb}$			<i>terminal to backside</i>	16,0	16,0	mm
$V_{ISOL}$	<i>isolation voltage</i>	$t = 1 \text{ second}$ $t = 1 \text{ minute}$ 50/60 Hz, RMS; $I_{ISOL} \leq 1 \text{ mA}$		4800		V
				4000		V

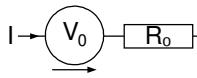


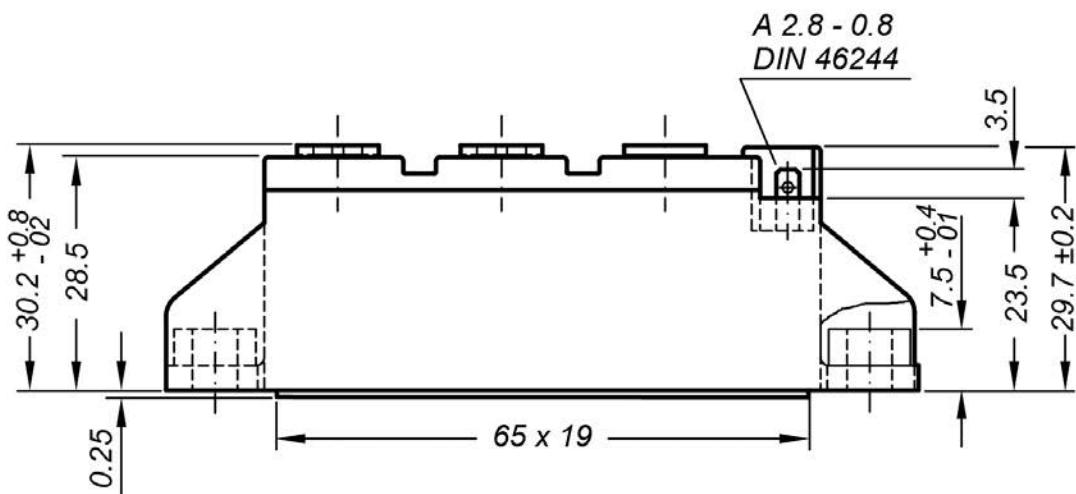
Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	MCC44-14io8B	MCC44-14io8B	Box	36	452963

Similar Part	Package	Voltage class
MCMA50P1600TA	TO-240AA-1B	1600
MCMA65P1600TA	TO-240AA-1B	1600

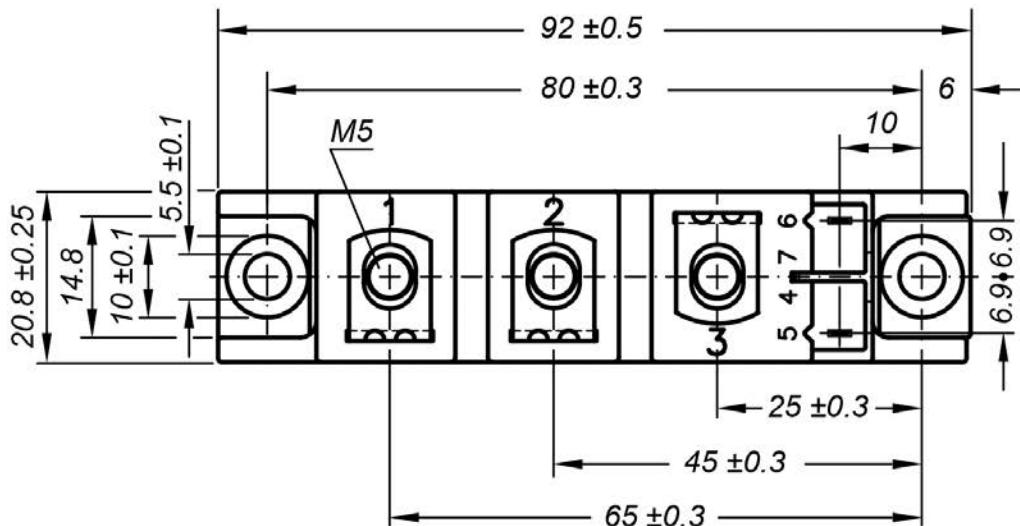
**Equivalent Circuits for Simulation**
<sup>\*</sup>on die level

 $T_{VJ} = 125^\circ\text{C}$ 

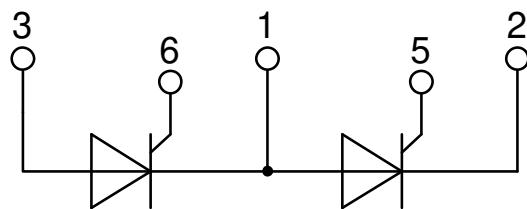
	<b>Thyristor</b>	
$V_0$		
$V_{0\ max}$	threshold voltage	0,85 V
$R_{0\ max}$	slope resistance *	4,1 mΩ

**Outlines TO-240AA**


General tolerance: DIN ISO 2768 class „c“


**Optional accessories for modules**

Keyed gate/cathode twin plugs with wire length = 350 mm, gate = white, cathode = red  
Type ZY 200L (L = Left for pin pair 4/5)      }  
Type ZY 200R (R = Right for pin pair 6/7)      } UL 758, style 3751



## Thyristor

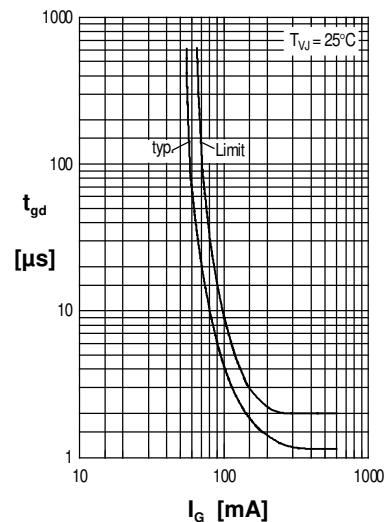
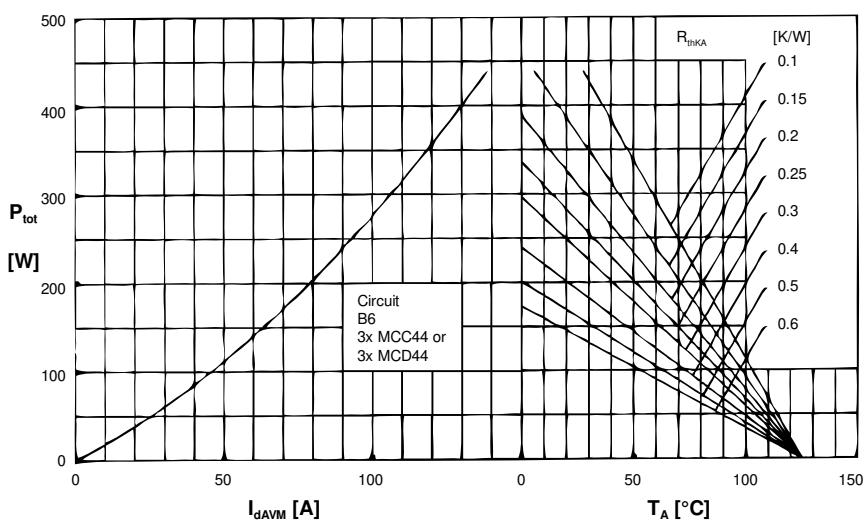
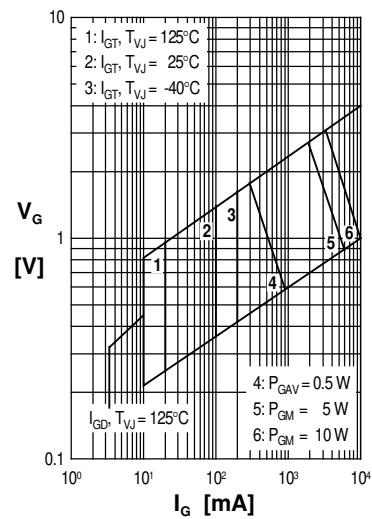
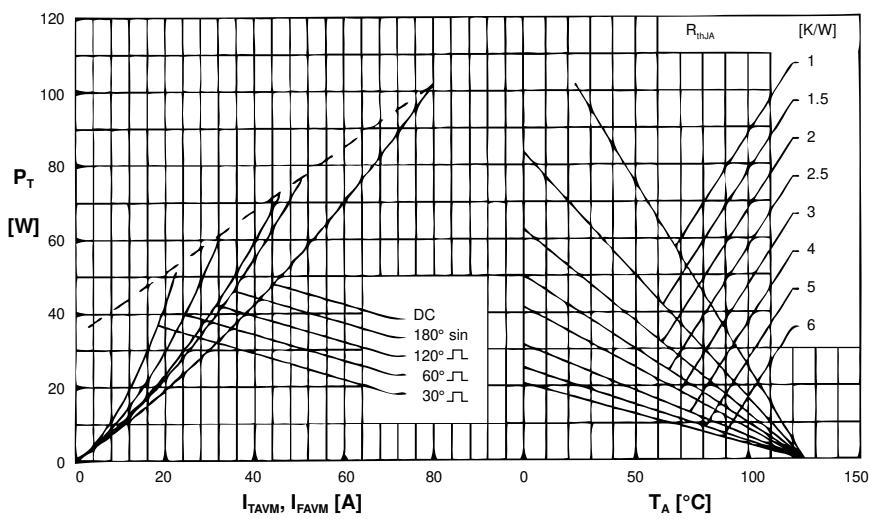
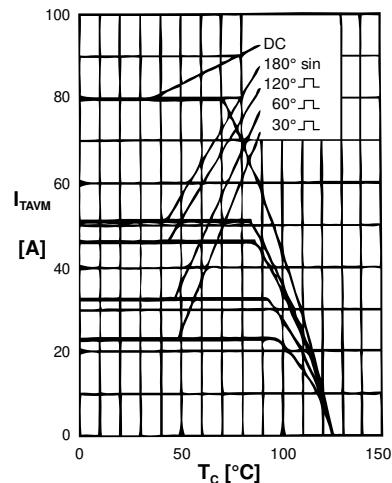
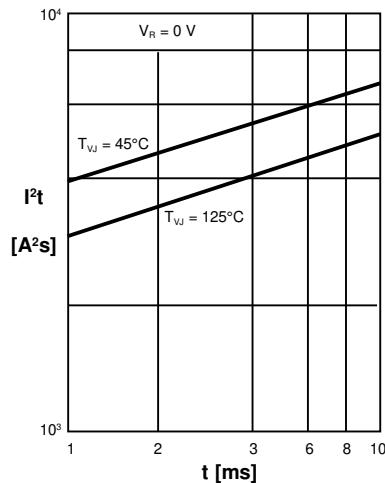
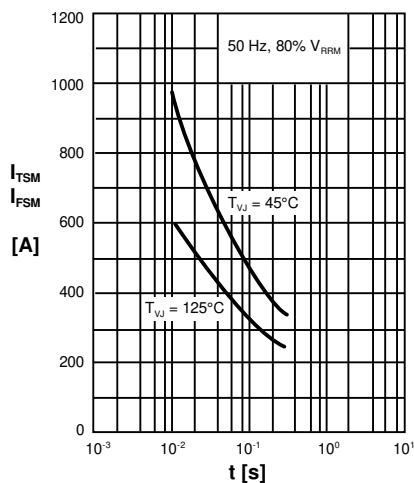


Fig. 6 Three phase rectifier bridge: Power dissipation versus direct output current and ambient temperature

Fig. 7 Gate trigger delay time

## Thyristor

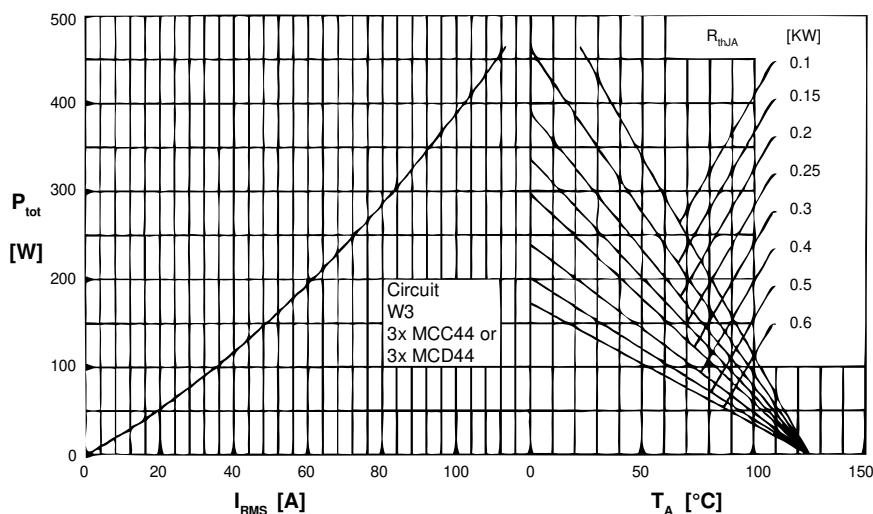


Fig. 8 Three phase AC-controller: Power dissipation versus RMS output current and ambient temperature

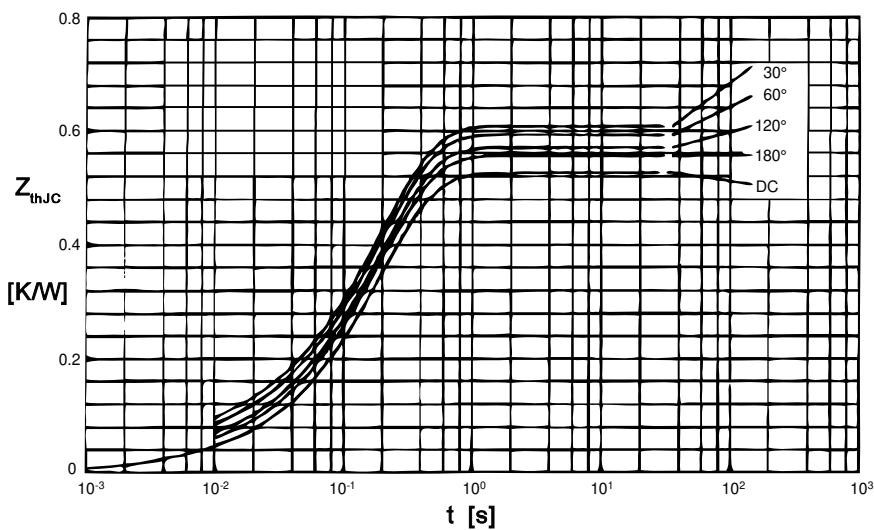


Fig. 9 Transient thermal impedance junction to case (per thyristor)

$R_{thJC}$  for various conduction angles  $d$ :

$d$	$R_{thJC}$ [K/W]
DC	0.53
180°	0.55
120°	0.58
60°	0.60
30°	0.62

Constants for  $Z_{thJC}$  calculation:

$i$	$R_{thi}$ [K/W]	$t_i$ [s]
1	0.015	0.0035
2	0.026	0.0200
3	0.489	0.1950

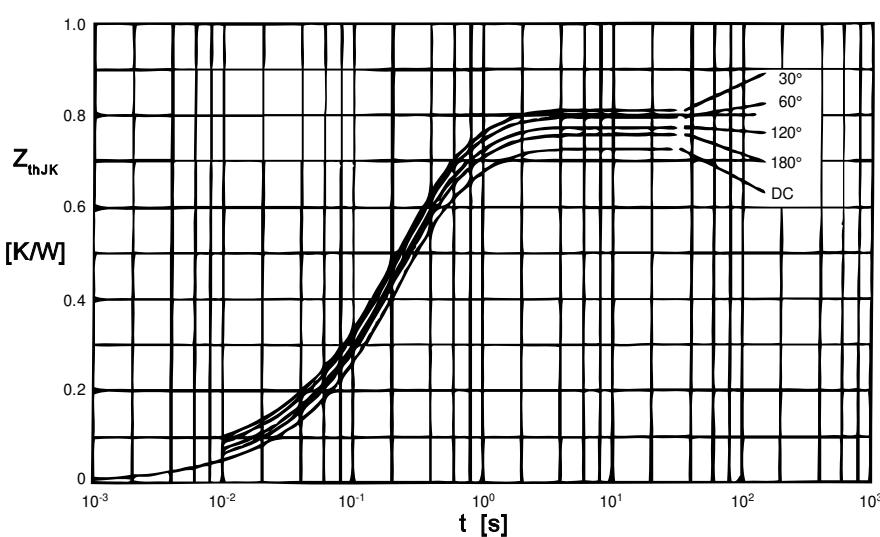


Fig. 10 Transient thermal impedance junction to heatsink (per thyristor)

$R_{thJK}$  for various conduction angles  $d$ :

$d$	$R_{thJK}$ [K/W]
DC	0.73
180°	0.75
120°	0.78
60°	0.80
30°	0.82

Constants for  $Z_{thJK}$  calculation:

$i$	$R_{thi}$ [K/W]	$t_i$ [s]
1	0.015	0.0035
2	0.026	0.0200
3	0.489	0.0195
4	0.200	0.6800